

MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

2N7002KQ-7-MS

Product specification

Features

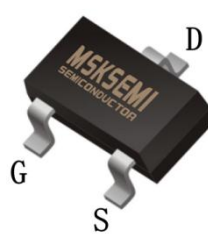
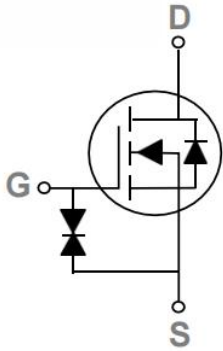

- 60V,0.3A, RDS(ON) =2.2Ω@VGS=10V
- Improved dv/dt capability
- Fast switching
- Green Device Available
- G-S ESD Protection Diode Embedded
- ESD protected up to 2KV

Application

- Motor Drive
- Power Tools
- LED Lighting

BVDSS	RDSON	ID
60V	2.2Ω	0.3A

Reference News

PACKAGE OUTLINE	Pin Configuration	Marking
 <p>SOT-23</p>		

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V _{DS}	Drain- Source Voltage	60	V
V _{GS}	Gate- Sou.ce Voltage	±20	V
I _D	Drain Current – Continuous (T _C =25°C)	0.3	A
	Drain Current – Continuous (T _C =100°C)	0.1	A
I _{DM}	Drain Current – Pulsed ¹	0.8	A
P _D	Power Dissipation (T _C =25°C)	0.35	W
	Power Dissipation – Derate above 25 °C	0.003	W/°C
T _{STG}	Storage Temperature Range	-50 to 150	°C
T _J	Operating Junction Temperature Range	-50 to 150	°C

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction to ambient	---	357	°C/W

Electrical Characteristics (T_J=25 °C , unless otherwise noted)

Off Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain- Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	60	---	---	V
I_{DSS}	Drain- Source Leakage Current	$V_{DS}=60V, V_{GS}=0V, T_J=25^\circ C$	---	---	1	μA
		$V_{DS}=48V, V_{GS}=0V, T_J=125^\circ C$	---	---	10	μA
I_{GSS}	Gate- Source Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	---	---	±10	μA

On Characteristics

$R_{DS(ON)}$	Static Drain- Source On- Resistance	$V_{GS}=10V, I_D=0.3A$	---	2.2	2.8	Ω
		$V_{GS}=4.5V, I_D=0.2A$	---	2.4	3.0	Ω
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=250\mu A$	1	1.6	2.5	V
g_{fs}	Forward Transconductance	$V_{DS}=10V, I_D=0.3A$	---	0.5	---	S

Dynamic and switching Characteristics

Q_g	Total Gate Charge ^{2, 3}	$V_{DS}=30V, V_{GS}=10V, I_D=1A$	---	3.7	5.6	nC
Q_{gs}	Gate-Source Charge ^{2, 3}		---	0.9	1.4	
Q_{gd}	Gate-Drain Charge ^{2, 3}		---	0.4	0.6	
$T_{d(on)}$	Turn-On Delay Time ^{2, 3}	$V_{DD}=30V, V_{GS}=10V, R_G=6\Omega$ $I_D=0.2A$	---	3	6	ns
T_r	Rise Time ^{2, 3}		---	5	10	
$T_{d(off)}$	Turn-Off Delay Time ^{2, 3}		---	14	27	
T_f	Fall Time ^{2, 3}		---	9	17	
C_{iss}	Input Capacitance	$V_{DS}=30V, V_{GS}=0V, F=1MHz$	---	25.5	38	pF
C_{oss}	Output Capacitance		---	17	26	
C_{rss}	Reverse Transfer Capacitance		---	7.8	12	

Drain-Source Diode Characteristics and Maximum Ratings

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_S	Continuous Source Current	$V_G=V_D=0V, \text{Force Current}$	---	---	0.3	A
I_{SM}	Pulsed Source Current		---	---	1.2	A
V_{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=1A, T_J=25^\circ C$	---	---	1.2	V
t_{rr}	Reverse Recovery Time	$V_{GS}=50V, I_S=1A, dI/dt=100A/\mu s$	---	3.4	---	ns
Q_{rr}	Reverse Recovery Charge	$T_J=25^\circ C$	---	0.7	---	nC

Note :

- 1.Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. The data tested by pulsed , pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. Essentially independent of operating temperature.

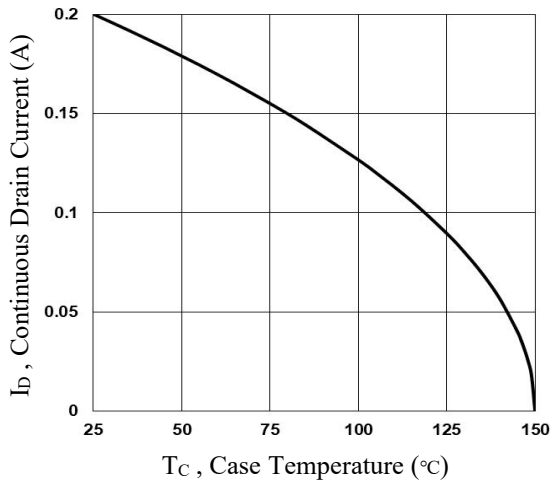


Fig.1 Continuous Drain Current vs. T_C

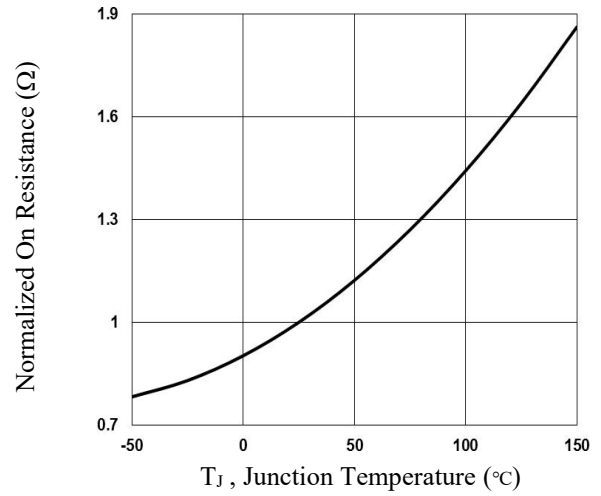


Fig.2 Normalized $R_{DS(on)}$ vs. T_J

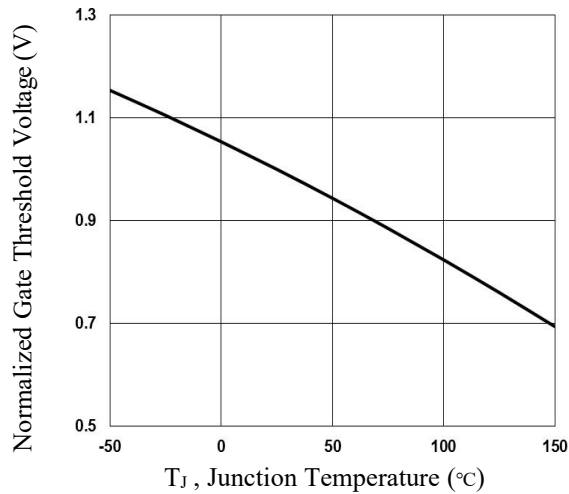


Fig.3 Normalized V_{th} vs. T_J

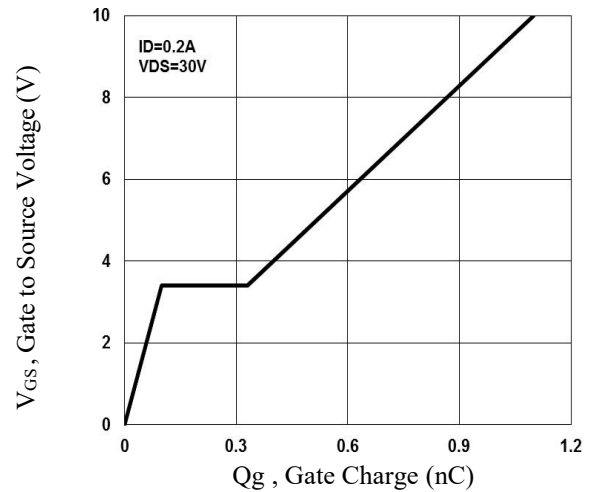


Fig.4 Gate Charge Waveform

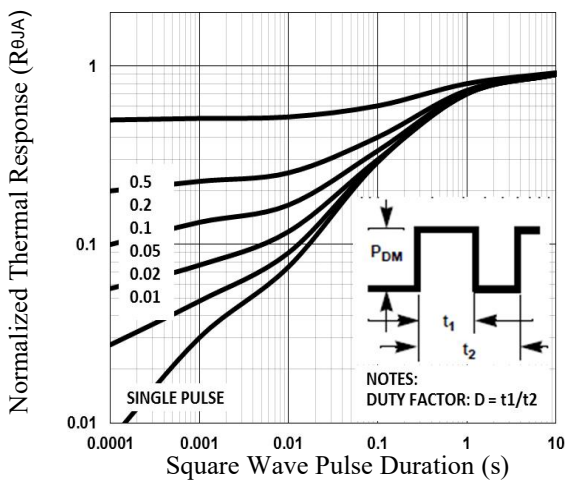


Fig.5 Normalized Transient Impedance

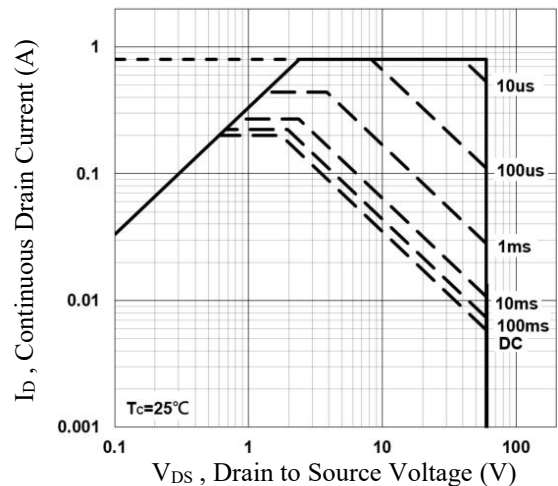
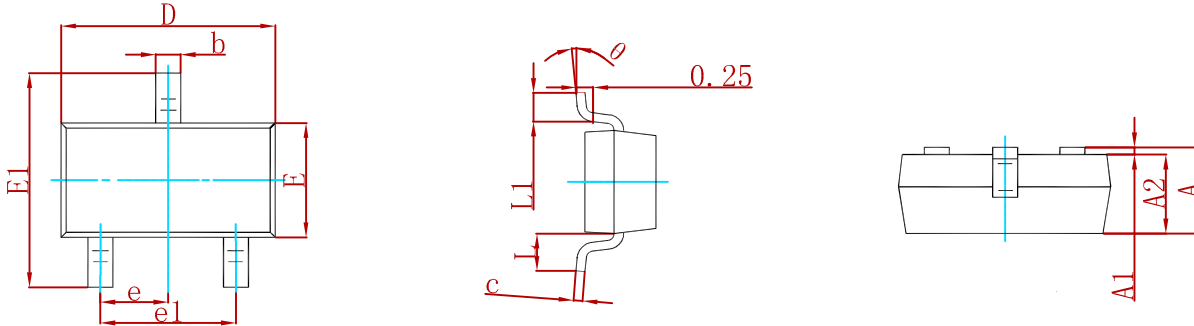


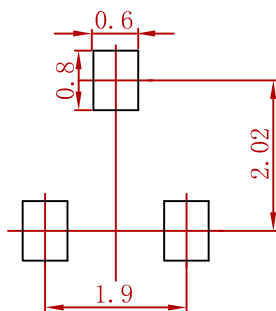
Fig.6 Maximum Safe Operation Area

PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05mm.
 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
2N7002KQ-7-MS	SOT-23	3000

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